DX200IH-CP01

Highly stabilized and precise fluxgate technology based current transducer, reengineered for cost sensitive, non-intrusive, isolated DC and AC current measurement applications up to 200A



Positive current direction

Features

DANI

- Linearity error maximum 6 ppm
- Offset maximum 40 ppm—equivalent to 1.5mA

Fluxgate, closed loop compensated technology with fixed excitation frequency and second harmonic zero flux detection for enhanced accuracy and stability

- Cost focused high performance transducer
- DC and AC current metering with +/-0.1% absolute accuracy up to 5kHz
- Necessary to ensure cooling on A5 when running higher currents.

Applications:

Compact stable power supplies

Specification highlights	Symbol	Unit	Min	Тур.	Max
Nominal primary AC current	IPN AC	Arms			140
Nominal primary DC current	IPN DC	А			200
Measuring range	ÎРМ	А	-220		220
Primary / secondary ratio	n1 : n2		1:1000		1:1000
Linearity error	ε _L	ppm	-6		6
Offset current (including earth field)	I _{OE}	ppm	-40		40
Operating temperature range	Та	°C	-40		60
Power supply voltages	Uc	V	±14.25		±15.75

Electrical specifications at Ta=23°C, supply voltage = ± 15V unless otherwise stated

Parameter	Symbol	Unit	Min	Тур.	Max	Comment
Nominal primary AC current	I _{PN} AC	Arms			140	Refer to fig. 1 & 2 for derating
Nominal primary DC current	I _{PN} DC	А	-200		200	Refer to fig. 1 for derating
Measuring range	I _{PM}	А	-220		220	Refer to fig. 1 & 2 for derating
Overload capacity	Î _{OL}	А			1000	Non-measured, 100ms
Nominal secondary current	I _{SN}	mA	-200		200	At nominal primary DC current
Primary / secondary ratio			1:1000		1:1000	
Measuring resistance	R _M	Ω	0		100	Refer to fig. 1 for details
Linearity error	£.	ppm	-6		6	ppm refers to nominal current
	υĽ	μA	-1.2		1.2	μA refers to secondary current
Offset current (including earth field)	I _{OE}	ppm	-40		40	ppm refers to nominal current
		μA	-8		8	µA refers to secondary current
Offset temperature coefficient	TC _{IOE}	ppm/K	-1		1	ppm refers to nominal current
		μA/K	-0.2		0.2	µA refers to secondary current
Bandwidth	f(-1dB)	kHz	300			Small signal, graphs figure 3
Response time to a step current IPN	tr @ 90%	μs		1		di/dt = 100A/µs
Noise 0 - 100Hz					10	
0 - 1kHz	noico	ppm			18	
0 - 10kHz	noise	rms			30	
0 - 100kHz					90	
Fluxgate excitation frequency	f _{Exc}	kHz		16		
Power supply voltages	Uc	V	±14.25		±15.75	
Positive current consumption	lps	mA			40	Add ls (if ls is positive)
Negative current consumption	Ins	mA			27	Add ls (if ls is negative)
Operating temperature range	Та	°C	-40		60	
Stability						
Offset stability over		ppm /	-5		5	ppm refers to nominal current
time		month	-1		1	μA refers to secondary current

Measurement resistor RM and ambient temperature derating (Fig. 1)

Maximum measurement resistor vs. ambient temperatures



Frequency and ambient temperature derating (Fig. 2)



Maximum primary current Arms

Frequency characteristics (Fig. 3)



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Isolation specifications

Parameter	Unit	Value
Clearance	mm	N/A
Creepage distance	mm	N/A
Comparative tracking index (CTI)	V	N/A
Rms voltage for AC isolation test, 50/60 Hz, 1 min - Between primary and (secondary and shield (GND))	kV	N/A
Impulse withstand voltage (1.2/50µs)	kV	N/A
Rated rms isolation voltage reinforced isolation, overvoltage category III, Pollution degree 2 according to IEC 61010-1 and EN50780	V	N/A N/A

Absolute maximum ratings

Parameter	Unit	Max	Comment
Primary	kA	1.5	Maximum 100ms
Power supply	V	±16.5	

Environmental and mechanical characteristics

Parameter	Unit	Min	Тур	Max	Comment
Operating temperature range	°C	-40		60	
Storage temperature range	°C	-40		85	
Relative humidity	%	20		80	Non-condensing
Mass	kg		0.200		
Connections	Samtec SSW-107-01-G-S				
Standards	EN 61326-1 EMC				

Positive current direction



Positive current direction

Positive current direction is from PCB side of transducer head.

Mounting instructions

Base plate mounting

4 holes ϕ 3.5